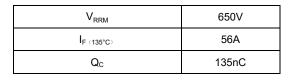
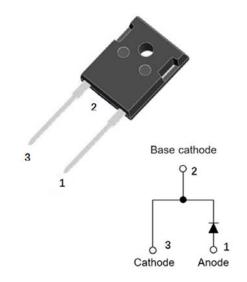


YJD106550NQG3

Silicon Carbide Schottky Diode





Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery voltage
- Essentially no switching losses
- Reduction of heat sink requirements
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- Package: TO-247AC Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (T_C=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D106550NQG3
Reverse voltage (repetitive peak) @ T _j =25°C	V _{RRM}	V	650
Reverse voltage (Surge Peak) @ T _j =25°C	V _{RSM}	V	650
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	650
Continuous forward current @ T _c =25°C			119
Continuous forward current @ T _c =135°C	IF	А	56
Continuous forward current @ T _c =143°C			50
Non-repetitive peak forward surge current @ $T_c=25^{\circ}C$, tp=10ms, Half Sine Wave	I _{FSM}	А	380
Power Dissipation@ T _c =25°C	Р	w	454
Power Dissipation@ T _c =110°C	P _{TOT}	vv	196
i²t Value@ Tc=25°C ,tp=10ms	∫i²dt	A ² S	722
Operating junction and Storage temperature range	T _j ,T _{stg}	°C	-55 to +175



Electrical Characteristics (Per Leg)

PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V _F	V	I _F =50A, T _j =25°C	1.45	1.6
			I _F =50A, T _j =175°C	1.9	-
Reverse leakage current	I _R	μΑ	V _R =650V, T _j =25°C	3	25
			V _R =650V, T _j =175°C	20	-
Total capacitive charge	Qc	nC	V_R =400V, T _j =25°C , QC= \int_0^{VR} C(V)dV	135.3	-
Total capacitance	С	pF	V _R =0V, f=1MHZ	2453	-
			V _R =200V, f=1MHZ	247	-
			V _R =400V, f=1MHZ	243	-
Capacitance Stored Energy	Ec	μJ	V _R =400V	16.5	-

■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	Value
Thermal resistance	R _{eJ-C}	°C W	0.33

■Typical Characteristics

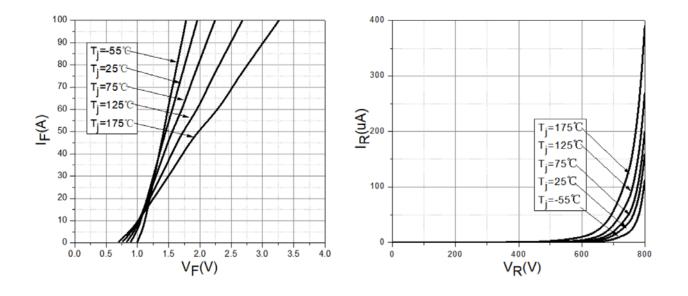
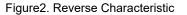


Figure 1. Forward Characteristics



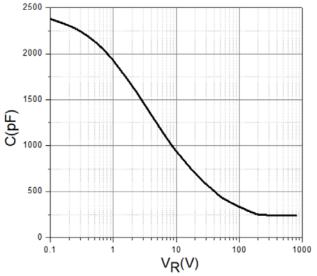


Figure 3. Capacitance vs. Reverse Voltage

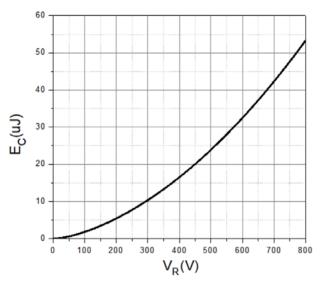


Figure 5. Capacitance Stored Energy

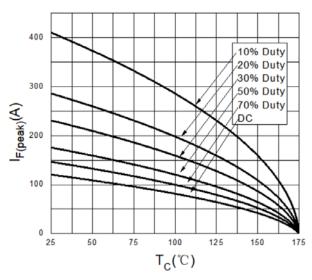


Figure 7. Current Derating

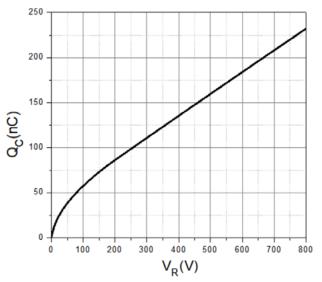
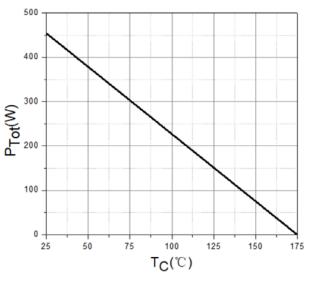
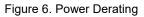
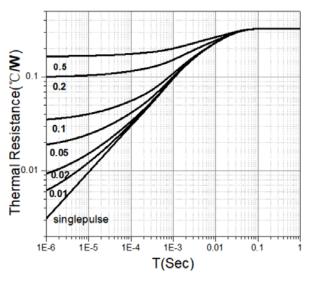


Figure 4. Total Capacitance Charge vs. Reverse Voltage







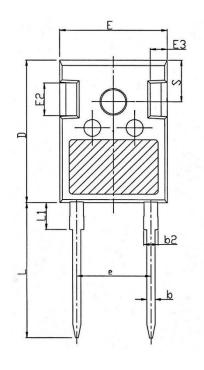


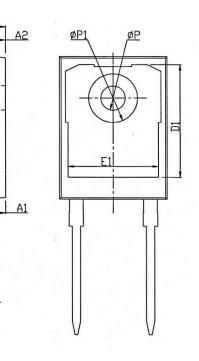


Outline Dimensions

TO-247AC

C





TO-247AC					
Dim	Min	Max			
Α	4.80	5.20			
A1	2.21	2.61			
A2	1.85	2.15			
b	1.11	1.36			
b2	1.91	2.21			
С	0.51	0.75			
D	20.70	21.30			
D1	16.25	16.85			
E	15.50	16.10			
E1	13.00	13.60			
E2	4.80	5.20			
E3	2.30	2.70			
е	10.88BSC				
L	19.62	20.22			
L1	-	4.30			
φP	3.40	3.80			
φ Ρ1	-	7.30			
S	6.15BSC				

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YJD106550NQG3

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